

## **N-Channel 30V MOSFET**

### **E030N6P0ML1**

V <sub>DS</sub> (V)	$R_{DS(on),max}$ (m $\Omega$ )	I <sub>D</sub> (A)
30V	6 @ V <sub>GS</sub> = 10V	30

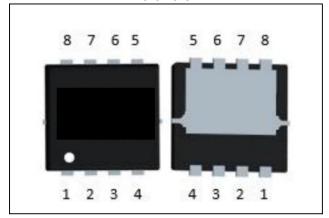
#### **Features**

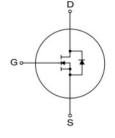
- Low R<sub>DS(on)</sub> trench technology
- Low thermal impedance
- Fast switching speed
- 100% avalanche tested

# **Applications**

- DC/DC conversion
- Power switch
- Moto driver

#### PDFN3.3X3.3







N-Channel

## **Package And Ordering Information**

Ordering code	Package	Marking
E030N6P0ML1	PDFN3.3*3.3	EX03N30

## **Ordering Information**

Package	Units/ Reel	Reels/ Inner Box	Units/ Inner Box
PDFN3.3*3.3	5000	1	5000



## **Key Performance Parameters**

Parameter	Value	Unit
VDS, min @ Tj(max)	30	V
ID, pulse	160	Α
RDS(ON), max @ VGS=10V	6	mΩ
Qg	27	nC

# Absolute Maximum Ratings at Tj=25°C Unless Otherwise Noted

Parameter	Symbol	Limit	Unit	
Drain-source voltage	$V_{DS}$	30		
Gate-source voltage		$V_{GS}$	±20	V
	T <sub>C</sub> =25°C		30	
Continuous drain current	T <sub>C</sub> =100°C	- I <sub>D</sub>	14	
Pulsed drain current	I <sub>D,pulse</sub>	160	А	
Avalanche energy, single pulse	E <sub>AS</sub>	25	mJ	
Dower discination	T <sub>C</sub> =25°C		30	
Power dissipation	T <sub>A</sub> =25°C	$P_{D}$	3.6	W
Operating junction and storage temperature range		T <sub>J</sub> , T <sub>stg</sub>	-55 to 150	℃

### **Thermal Characteristics**

Parameter		Symbol	Max.	Unit
Thermal resistance, junction-to-case	Steady state	Rejc	4.9	
Thermal resistance, junction-to-ambient	Steady state	$R_{ heta JA}$	42	°C/W

# Electrical Characteristics at Tj=25°C unless otherwise specified

Parameter	Symbol	Min.	Тур.	Max.	Unit	Test conditions	
Static							
Drain to source breakdown voltage	V <sub>(BR)DSS</sub>	30			>	V <sub>GS</sub> = 0, I <sub>D</sub> = 250 μA	
Gate-source threshold voltage	V <sub>GS</sub> (th)	1.3	1.65	2.4	V	V <sub>DS</sub> = V <sub>GS</sub> , I <sub>D</sub> = 250 μA	
Gate-body leakage	I <sub>GSS</sub>			±100	nA	V <sub>DS</sub> = 0 V, V <sub>GS</sub> = ±20 V	
Zero gate voltage drain current	I <sub>DSS</sub>			1	μΑ	V <sub>DS</sub> = 30 V, V <sub>GS</sub> = 0 V	
Drain-source on-resistance	Ros(on)		5.2	6	mΩ	V <sub>GS</sub> = 10 V, I <sub>D</sub> = 15 A	
Drain-source on-resistance	Ros(on)		7.8	10	mΩ	V <sub>GS</sub> = 4.5 V, I <sub>D</sub> = 10 A	
Gate resistance	Rg	0.2	2	5	Ω	f=1MHz	



Gate Charge							
Total gate charge	Qg		27	47			
Gate-source charge	Qgs		4.5	7.9	nC	V <sub>DS</sub> = 15 V, I <sub>D</sub> = 15 A, V <sub>GS</sub> = 10 V	
Gate-drain charge	Qgd		5	8.8			
			Dynamic	;			
Turn-on delay time	$t_{d(on)}$		6.4				
Rise time	t <sub>r</sub>		51			V <sub>DS</sub> = 15 V, I <sub>D</sub> =15 A, V <sub>GS</sub> = 10 V,	
Turn-off delay time	$t_{d(off)}$		25		ns	$R_{GEN} = 3 \Omega$	
Fall time	$t_f$		15		110		
Input capacitance	C <sub>iss</sub>	415		2430			
Output capacitance	C <sub>oss</sub>	80		970		V <sub>DS</sub> =15 V, V <sub>GS</sub> = 0 V, f = 1MHz	
Reverse transfer capacitance	C <sub>rss</sub>	30		245	pF		
Body Diode							
Diode forward voltage	$V_{\text{SD}}$		0.8	1.2	V	V <sub>GS</sub> = 0 V, I <sub>F</sub> = 15A	
Reverse recovery time	t <sub>rr</sub>		7	28	ns	V <sub>R</sub> = 0 V, I <sub>S</sub> =15 A, di/dt = 100	
Reverse recovery charge	Qrr		1.4	6.4	nC	A/µs	

## **Electrical Characteristics Diagrams**

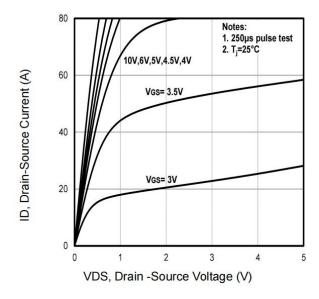


Fig1. Typical Output Characteristics

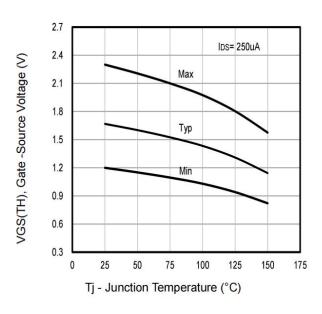
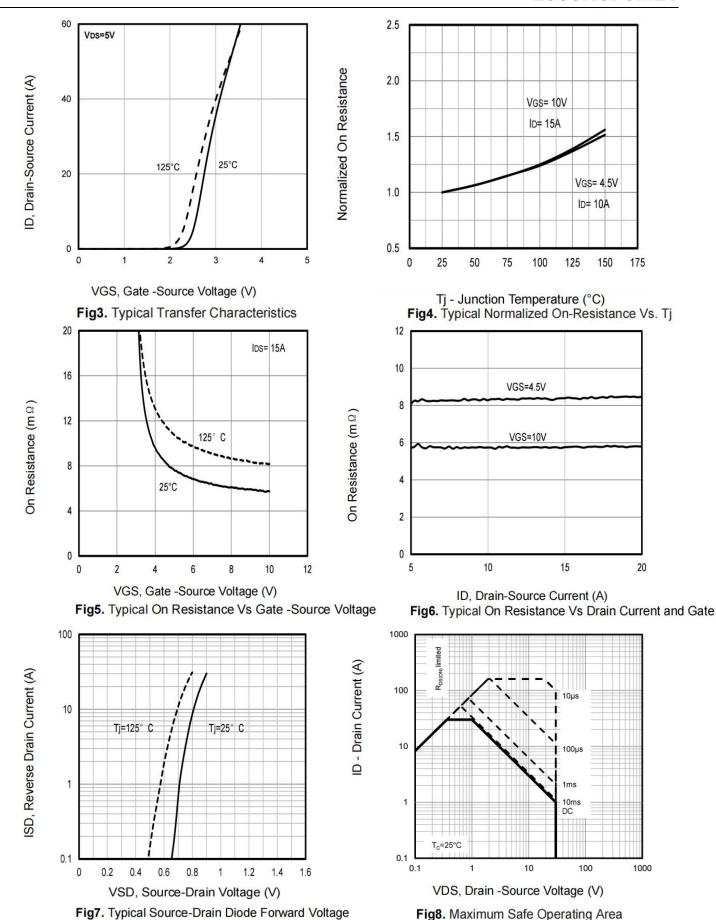
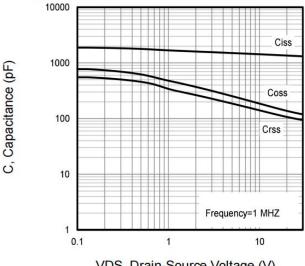


Fig2. Typical V<sub>GS(TH)</sub> Gate -Source Voltage Vs. Tj

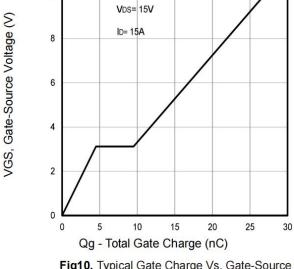








VDS, Drain-Source Voltage (V) Fig9. Typical Capacitance Vs. Drain-Source Voltage



10

Fig10. Typical Gate Charge Vs. Gate-Source Voltage

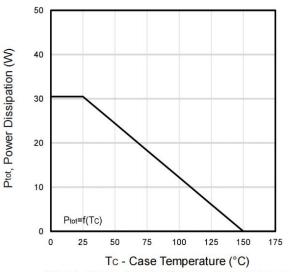


Fig11. Power Dissipation Vs. Case Temperature

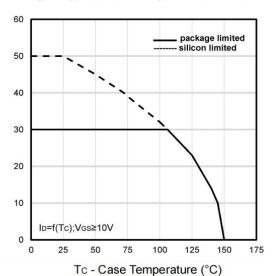
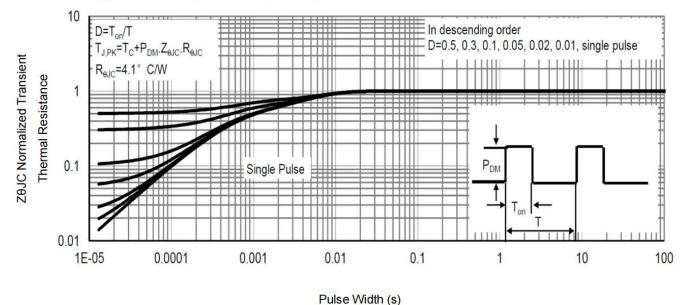


Fig12. Maximum Drain Current Vs. Case Temperature



D, Maximum Drain Current (A)

Fig13 . Normalized Maximum Transient Thermal Impedance



#### Test circuits and waveforms

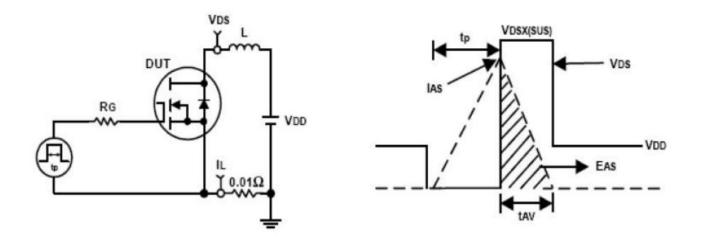


Fig1. Unclamped Inductive Test Circuit and waveforms

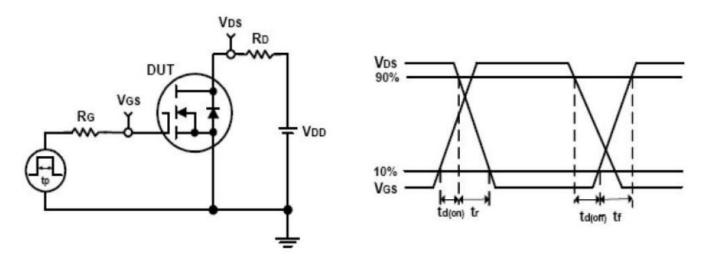
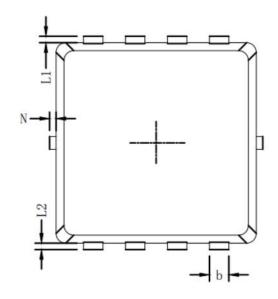


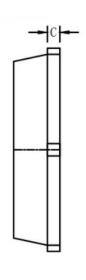
Fig2. Switching Time Test Circuit and waveforms

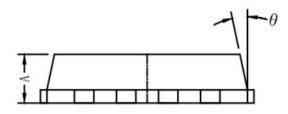


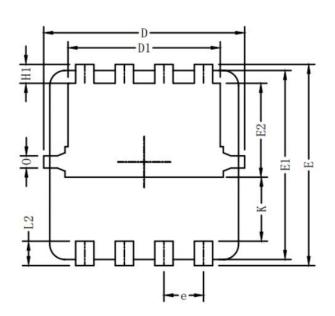
# **Package Outline Dimensions**

# PDFN3.3\*3.3









Crowb a La	Millimeters					
Symbols	MIN.	NOM.	MAX.			
A	0.65	0.75	0.85			
b	0. 25	0.30	0.35			
C	0.15	0. 20	0.25			
D	3.00	3. 10	3. 20			
D1	2.40	2.50	2.60			
Е	3. 20	3. 30	3. 40			
E1	3.00	3. 10	3. 20			
E2	1.60	1.70	1.80			
е	(	. 65 BSC				
H1	0.21	0.31	0.41			
Н2	0.30	0.40	0.50			
K	0.95	1.05	1.15			
L1/L2	0.10 REF.					
θ	11°	12°	13°			
N	0	-	0. 15			
0	0. 2 REF.					



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